Demonstration of chalcogenide glass racetrack micro-resonators

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We have demonstrated the first chalcogenide glass racetrack micro-resonator using a CMOS-compatible lift-off technique with thermally evaporated As2S3 films. The device features a small footprint of 0.012 mm2, a cavity Q (quality factor) of 10,000 and an extinction ratio of 32 dB, simultaneously. These resonators exhibit a very high sensitivity to refractive index changes, with a demonstrated detection capability of \( \Delta n_{\text{As2S3}} = (4.5 \times 10^{-6} \pm 10\%) \) RIU (Refractive Index Unit). The resonators were applied to derive photorefractive response of As2S3 to \( \lambda = 550 \) nm light. The resonator devices are a versatile platform for both sensing and glass material property investigation. © 2007 Optical Society of America

In an optical resonator, circulating light is confined within a small volume. When the resonant condition is met, the optical power becomes resonantly enhanced up to a factor approximating cavity finesse. Such resonant enhancement, combined with a significantly increased optical path length, makes ring and racetrack resonators an ideal device platform for both fundamental investigations and practical applications based on photon-matter interactions. The examples include all-optical switching\(^1\), light emission\(^2\), nonlinear optics\(^3\), and biochemical sensing\(^4\). Chalcogenide (ChG) glasses have been identified to be a promising material candidate for the aforementioned applications due to their unique optical properties in the infrared. Of particular relevance here are the photosensitivity, reduced phonon quenching, large Kerr optical nonlinearity, and wide infrared transparency window\(^5\) of ChG materials. Thus, a micro-resonator in chalcogenide glasses that maximizes the leverage of their properties becomes highly desirable.

Here we present the first demonstration of chalcogenide glass racetrack resonators in thermally evaporated \(\text{As}_2\text{S}_3\) films. We have also shown that such resonators can be used as ultra-sensitive probes of photosensitivity in chalcogenide glass, providing unprecedented high accuracy measurement (on the order of \(10^{-6}\) RIU) of photorefractive index change.

The bulk preparation and film deposition process are described elsewhere\(^6\), \(^7\). These devices were patterned by lift-off, and the whole patterning process has been carried out on a 500 nm CMOS line\(^8\). The CMOS-compatibility allows this process to be scaled up for mass production. The racetracks are comprised of strip waveguides with a width of 800 nm and a height of 450 nm. After patterning, a layer of 3 \(\mu\)m thick SU8 polymer was spin-coated to serve as the top cladding. The device was subsequently annealed at 130°C for 3 hours to stabilize the glass structure. Figure 1 shows the top view of a fabricated resonator. The fabricated device has a small footprint of 0.012 mm\(^2\), and the total cavity length is \(\sim 409\) \(\mu\)m.
Transmission spectra of the fabricated device have been measured on a Newport AutoAlign workstation in combination with a tunable laser (optical vector analyzer external laser, LUNA Technologies, Inc.). Lens-tip fibers are used to couple light from the laser into and out of the devices. Reproducible coupling is achieved via an automatic alignment system with a spatial resolution of 50 nm. The sample was mounted on a thermostat stage and kept at 25 °C for all measurements. Figure 2(a) shows a measured transmission spectrum of TM polarization. The resonator has a Free Spectral Range (FSR) of 2.5 nm and a maximum extinction ratio of 32 dB near 1550 nm. Such a high extinction ratio indicates that the resonator works near the critical coupling regime. Cavity Q, defined as the ratio of wavelength against 3 dB resonant peak width, was determined from Fig. 2(b) to be ~10,000. This Q value corresponds to an equivalent waveguide loss of 16.5 dB/cm. We expect that an optimized fabrication process with minimized pattern digitization error of waveguide bends, post-fabrication smoothing and GRIN waveguide design could further reduce waveguide loss, leading to even higher Q factors. For comparison, photonic crystal cavities in Ge33As12Se55 chalcogenide glass have recently been demonstrated with a similar Q of 10,000 and an extinction ratio up to 2.6 dB.

An important feature of resonators is their extreme sensitivity to refractive index changes, and thus they have been proposed to be a promising candidate for miniaturized biochemical sensors. This property can also be utilized to probe micro-structural evolution in chalcogenide glasses, since structural modifications in these glasses are often accompanied by a refractive index change. In addition, accurate determination of the index change is also technically important for applications that rely on photo-induced index modifications such as direct laser writing. For example, Zoubir et al. measured an index increase up to 0.08 at 785 nm wavelength in femtosecond laser written As2S3 waveguides. Often, the spectrum from a single scan has low...
Signal-to-Noise Ratio (SNR) and does not allow accurate determination of index change. For this reason, we have used multiple scan averaging over a single resonant peak to improve SNR and wavelength resolution. By averaging over 64 individual scans, noise in the transmission spectrum is suppressed, as is evident in Fig. 2(b).

To study the photosensitivity of As$_2$S$_3$, the resonator device was exposed to timed near-bandgap light (~550 nm wavelength with an irradiance of 6.2 mW/cm$^2$ from a band pass filtered halogen lamp) to induce a controlled refractive index change using a setup schematically shown in Fig. 3(a), and the resulting peak shift was monitored in-situ. A Lorentzian fit has been used to extract the accurate peak position. Refractive index change can be calculated via:

$$
\Delta n = \frac{\Delta \lambda}{\lambda} \times \frac{n_{\text{eff}}}{\Gamma}
$$

(1)

where $\Delta \lambda$ stands for the resonant peak shift, $n_{\text{eff}}$ is the waveguide effective index, and $\Gamma$ is the confinement factor in As$_2$S$_3$ core. Finite-difference simulations give $n_{\text{eff}}$ and $\Gamma$ of TM polarization to be 1.88 and 0.77, respectively.

Figure 3(b) gives an example of two spectra with a peak shift of $(3 \pm 0.3)$ pm after light exposure, corresponding to an index increase of $4.5 \times 10^{-6} \pm 10\%$ in As$_2$S$_3$ at 1597 nm wavelength. The wavelength resolution of 0.3 pm was statistically determined by repeating the experiment and comparing multiple measurement results. Such a high sensitivity is essential especially for accurate photosensitivity measurement in annealed glass, which exhibits much smaller photo-induced index change compared to its as-deposited counterpart.$^{14}$

Figure 4 shows the refractive index increase at 1550 nm wavelength as a function of exposure dose for both as-deposited (without annealing) and annealed As$_2$S$_3$ devices. Excellent
data reproducibility was confirmed by repeating the measurement on several resonators. In both cases the index increase can be well described with a single-exponential function:

$$\Delta n = \Delta n_{\text{sat}} \times [1 - \exp(-D/D_0)]$$

where $\Delta n_{\text{sat}}$ is the maximum index change when the photorefractive effect has been fully saturated, $D$ represents the exposure dose in J/cm$^2$ and $D_0$ is a material constant which depends on processing history. Our results confirm the validity of exponential empirical fit in previous reports$^{15,16}$. For unannealed As$_2$S$_3$, $\Delta n_{\text{sat}} = 0.0505 \pm 0.0002$, $D_0 = (0.036 \pm 0.001)$ J/cm$^2$, whereas for annealed As$_2$S$_3$, $\Delta n_{\text{sat}} = 0.0125 \pm 0.0001$, $D_0 = (0.024 \pm 0.001)$ J/cm$^2$. The smaller photo-induced index change in annealed glass has also been observed by C. Lopez in As$_2$S$_3$ films prepared by the same deposition technique, irradiated with an 800 nm femtosecond laser and measured using an ellipsometer$^{14}$.

It is also important to note that the annealed and unannealed samples have distinctive $D_0$ values, which indicate different micro-structural modifications. This finding confirms that photosaturated state and thermally annealed state are structurally dissimilar in chalcogenide glasses$^{14,17}$.

To summarize, we have demonstrated the first chalcogenide glass racetrack micro-resonator in thermally evaporated As$_2$S$_3$ film with a Q factor of 10,000 and an extinction ratio of 32 dB, providing a versatile platform for nonlinear optics, light emission and sensing using chalcogenide materials. These devices can detect refractive index change as small as $4.5 \times 10^{-6}$ in As$_2$S$_3$ with good SNR, and thus are also useful tools for probing micro-structural evolution in glasses.
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References


Fig. 1. Optical micrograph of a fabricated resonator device; inset SEM micrograph shows the coupling region between the coupling (bus) waveguide and the racetrack.

Fig. 2. Transmission spectra of TM polarization in a resonator device: (a) the resonator exhibits an FSR of 2.5 nm and an extinction ratio of 32 dB; (b) the resultant spectrum averaged over 64 consecutive scans.

Fig. 3. (a) Photosensitivity measurement setup; (b) Transmission spectra of a resonator in the proximity of its resonant peak. Black dots represent experimental data points, and the red dots are data measured in the same device after exposure to ~550 nm wavelength light; the curves are
fitted Lorentzian peaks. A wavelength shift of \((3 \pm 0.3)\) pm is determined by peak fit, corresponding to an index change of \((4.5 \times 10^{-6} \pm 10\%)\) RIU in As₂S₃ at 1597 nm wavelength.

Fig. 4. Photo-induced refractive index change as a function of exposure dose (\(\lambda = 550\) nm) in an as-deposited, unannealed resonator and in a resonator annealed at 130°C for 3 hours.